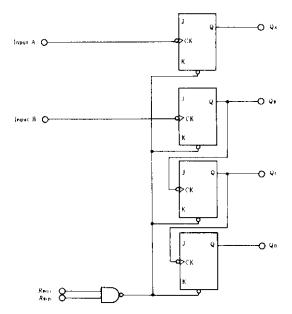
The HD74LS93 contains four master-slave flip-flops and additional gating to provide a divide-by-two counter and threestate binary counter for divide-by-eight. To use this maximum count length of this counter, the B input is connected to the Q_A output. The input count pulses are applied to input A and the outputs are described in the appropriate function table.

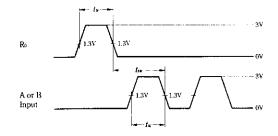
BLOCK DIAGRAM



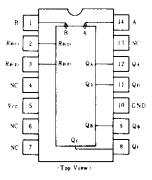
RECOMMENDED OPERATING CONDITIONS

Iter	מ	Symbol	min	typ	max	Unit	
Count A inp		,	0		32	MIL	
frequency	B input	frount	0	_	16	MHz	
	A input		15				
Pulse width	B input	tw.	30	-		ns I	
	Reset inputs		15		_		
Setup time		tru	25		T	ns	

TIMING DEFINITION



PIN ARRANGEMENT



■ABSOLUTE MAXIMUM RATINGS

Item		Symbol	Ratings	Unii	
Supply vo	ltage	Vec	7.0	V	
Input	R Inputs		7.0	V	
voltage	A, B Inputs	Vin	5.5	v	
Operating temperature range		Topr	- 20 - + 75	Ċ	
Storage temperature range		Tate	- 65 + 150	°C	

FUNCTION TABLE

Reset/Count Function Table

Reset	Inputs		Out	puts	
R0m	R0(2)	QD	Qc	Qв	QA
Н	н	L	L	L	L
L	×		Co	unt	
×	L		Co	unt	

BCD Count Sequence (Notes 1)

		Out	puts	
Count.	Qp	Qc	QB	QA
0	L	L	L	Ĺ
1	L	L] L	Н
2	L	L	н	L
3	L	L	н	н
4	L	н	L	L
5	L	Н	L	H
6	L	Н	H	L
7	L	н	H	Н
8	н	L	L	L
9	Н	L	L	Н
10	н	L	н	L
11	н	L	Н	Н
12	н	н	Ł	L
13	Н	н	L	Н
14	Н	Н	Н	L
15	н	Н	н	н

Notes) 1. Output Q_A is connected to input B for BCD count. 2. H; high level, L; low level, X; irrelevant

ELECTRICAL CHARACTERISTICS ($Ta = -20 \sim +75^{\circ}C$)

Iter	m	Symbol	Test Conditions		min	typ*	max	Unit
		Vin			2.0	-	-	v
Input voltage		VIL			_	_	0.8	v
		Voн	$V_{CC} = 4.75V, V_{IH} = 2V, V_{IL} = 0.8V$	<i>і, Іон=−</i> 400µА	2.7	_		v
Output voltage	Jutput voltage		$V_{cc} = 4.75 V, V_{lH} = 2 V,$	IoL=4mA**		_	0.4	
• •		Vol	$V_{IL}=0.8V$	$lo_L = 8mA^{**}$	_		0.5	v
	Any Reset		$V_{CC} = 5.25 \text{V}, V_i = 0.4 \text{V}$			-	-0.4	mA
	A input	In			_	_	-2.4	
	B input					_	-1.6	
	Any Reset				-	-	20	
Input current	A input	Ін	$V_{cc} = 5.25 V, V_l = 2.7 V$			-	40	μA
	B input				-	-	40	
	Any Reset			$V_l = 7 V$	-	_	0.1	
	A input	Iı	$V_{cc} = 5.25 V$	$V_l = 5.5 V$	-	-	0.2	mA
	B input			$V_{I} = 5.5 V$	-	-	0.2	
Short-circuit ou	tput current	los	Vec = 5.25V		- 20	_	- 100	mA
Supply current		Icc***	$V_{\rm CC} = 5.25 \mathrm{V}$		_	9	15	mA
Input clamp volta	age	Vik	$V_{CC} = 4.75 \text{V}, I_{LN} = -18 \text{m/s}$	A [-	-	-1.5	v

V_{CC}=5V, Ta=25°C
 * Q_A output is tested at specified I_{OL} plus the limit value of I_{IL} for the B input. This permits driving the B input while maintaining full fan-out capability.

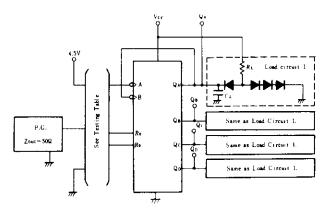
*** I_{CC} is measured with all outputs open, both R_0 inputs grounded following momentary connection to 4.5V, and all other inputs grounded.

SWITCHING CHARACTERISTICS ($V_{CC} = 5V$, $T_a = 25^{\circ}C$)

Item	Symbol	Inputs	Outputs	Test Conditions	min	typ	тах	Unit	
		A	QA		32	42	-	MHz	
Maximum count frequency	fmax	В	Qв		16			MHZ	
	tplH		_		-	10	16		
	tphL	A	Q.A		-	12	18	ns ns	
	tPLH				-	46	70	ns ns ns	
	tPHL	A	Qυ		-	46	70		
	tPLH	В	0	$C_L = 15 \mathrm{pF}, R_L = 2 \mathrm{k} \Omega$	-	10	16		
Propagation delay time	tphi.		в	QB		-	14	21	n:
	tplH		Qc			-	21	32	T
	tphL	B B			-	23	35] ⁿ	
	tpl.h				-	34	51		
	tPHL		B QD		_	34	51	ns	
	t PHL	Set-to-0	QA~QD		-	26	40	n:	

TESTING METHOD

1) Test Circuit

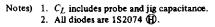


2) Testing Table

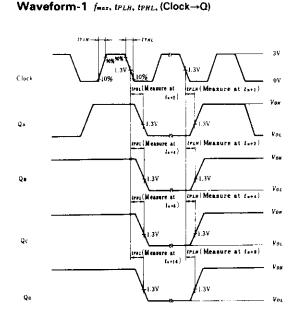
ltem	From input		Inputs			Out	puts	
Item	to output	A	В	Ro	Qa	Qa	Qc	Qu
{max	A →Q	IN	to QA	GND	Out	Out	Out	Out
<i>)</i> m a <i>i</i>	B →Q	4.5V	IN	GND		Out	Out	Out
	A →QA	IN	to QA	GND	Out	-	-	-
	A →Q _D	IN	to QA	GND	-	-		Out
ı₽LĦ	B →Q _B	4.5V	IN	GND		Out	-	
IPHL	B →Qc	4.5V	IN	GND	-	· -	Out	_
	B →Q₀	4.5V	IN	GND	-	-	-	Out
	Rð⊷Q	IN*	to QA	IN	Out	Out	Out	Out

* For initialized.

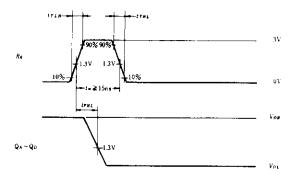
** Measured with each input and unused inputs at 4.5V.





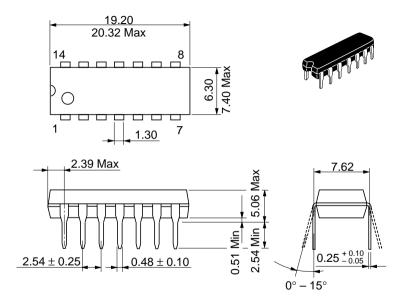


- Notes) 1. Input pulse; tTLH 15ns, tTHL 5ns, PRR=1MHz, duty cycle=50% and: for f_{max} , $t_{TLH}=t_{THL} \leq 2.5$ ns. 2. t_n is reference bit time when all outputs are low.



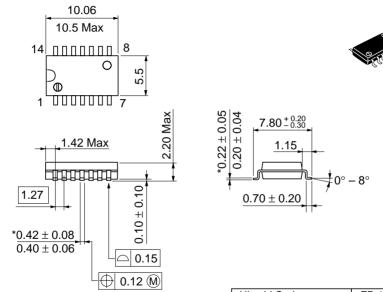
Notes) 1. $t_{TLH} \leq 15$ ns, $t_{THL} \leq 5$ ns.

Unit: mm



Hitachi Code	DP-14
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.97 g

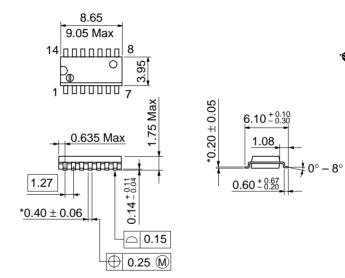
Unit: mm



*Dimension including the plating thickness Base material dimension

Hitachi Code	FP-14DA
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.23 g

Unit: mm



Hitachi Code	FP-14DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.13 g

*Pd plating

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